

## 1A, 50V - 1000V Surface Mount Rectifiers

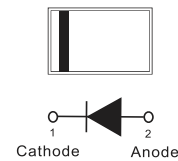
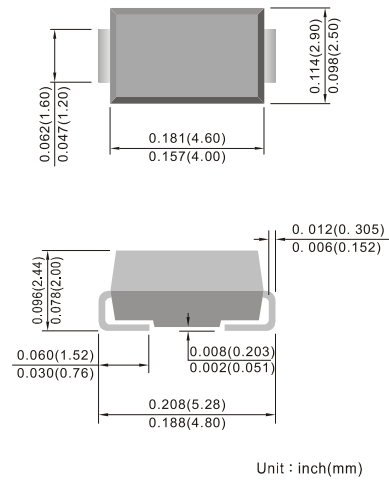
### FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

### MECHANICAL DATA

- **Case:** DO-214AC (SMA)  
Molding compound, UL flammability classification rating 94V-0  
Moisture sensitivity level: level 1, per J-STD-020
- **Terminal:** Matte tin plated leads, solderable per JESD22-B102  
Meet JESD 201 class 2 whisker test
- **Polarity:** Indicated by cathode band
- **Weight:** 0.06 g (approximately)

### DO-214AC (SMA)



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	GS1A	GS1B	GS1D	GS1G	GS1J	GS1K	GS1M	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I <sub>F(AV)</sub>	1							A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30							A
Maximum instantaneous forward voltage (Note 1) @ 1 A	V <sub>F</sub>	1.1							V
Maximum reverse current @ rated V <sub>R</sub> T <sub>J</sub> =25°C T <sub>J</sub> =125°C	I <sub>R</sub>	1 50							μA
Typical reverse recovery time (Note 2)	t <sub>rr</sub>	1.5							μs
Typical junction capacitance (Note 3)	C <sub>J</sub>	12							pF
Non-repetitive peak reverse avalanche energy at 25°C, I <sub>AS</sub> =1A, L=10mH	E <sub>RSM</sub>	5							mJ
Typical thermal resistance	R <sub>θJL</sub> R <sub>θJA</sub>	27 75					30 85		°C/W
Operating junction temperature range	T <sub>J</sub>	- 55 to +175							°C
Storage temperature range	T <sub>STG</sub>	- 55 to +175							°C

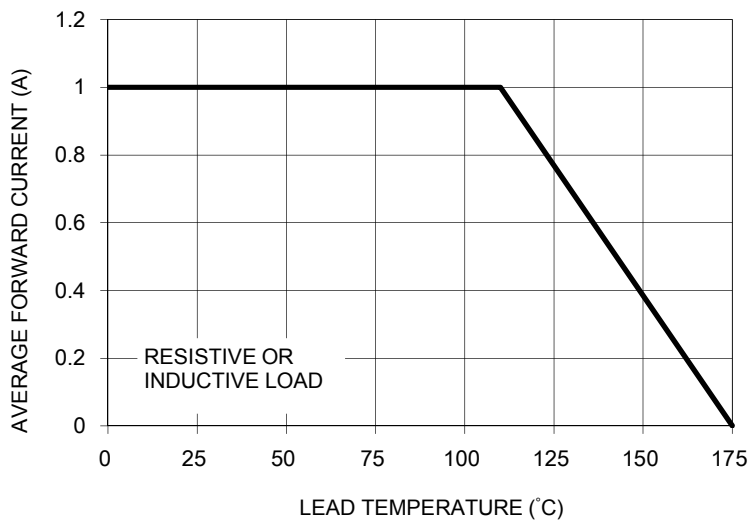
Note 1: Pulse test with PW=300μs, 1% duty cycle

Note 2: Reverse Recovery Test Conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

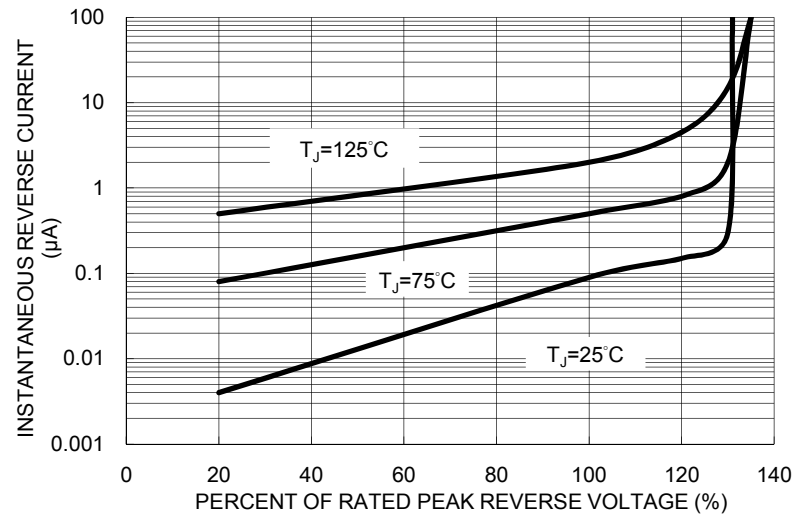
Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

**RATINGS AND CHARACTERISTICS CURVES ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

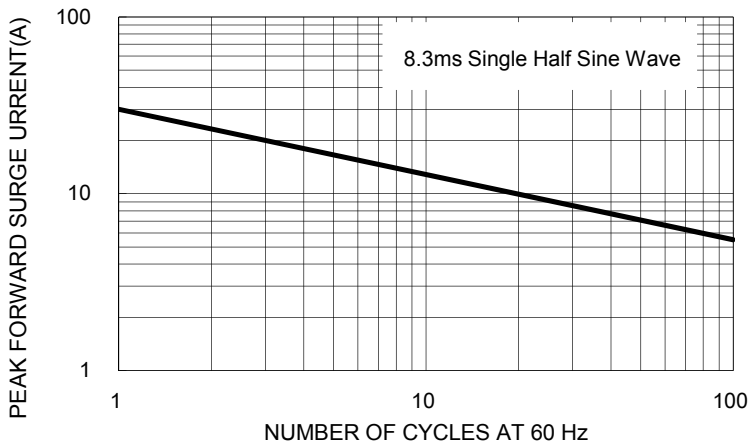
**FIG.1 FORWARD CURRENT DERATING CURVE**



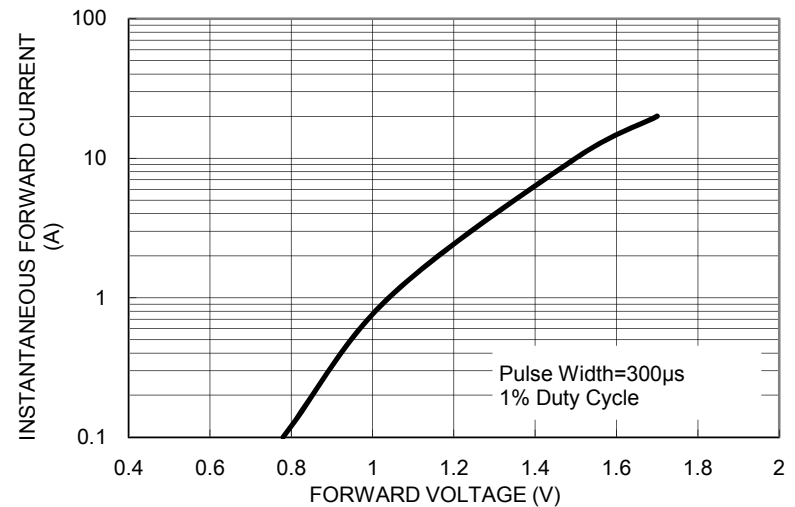
**FIG. 2 TYPICAL REVERSE CHARACTERISTICS**



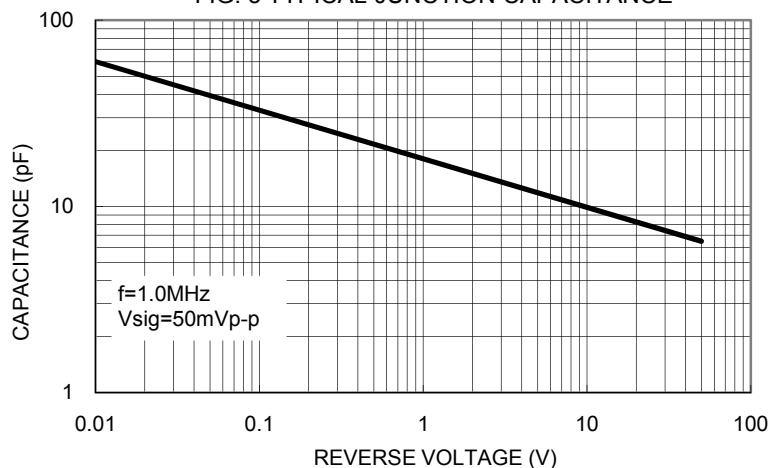
**FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT**



**FIG. 4 TYPICAL FORWARD CHARACTERISTICS**



**FIG. 5 TYPICAL JUNCTION CAPACITANCE**



**FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**

